

SANYO Semiconductors

DATA SHEET

SMA3103 -

Silicon MMIC Wideband Amplifier

Features

- High Gain : Gp=26.5dB typ. @1GHz
- Wideband response : fu=3.3GHz
- Low current : ICC=19mA typ
- High output power : Po(1dB)=5dBm
- Port impedance : input/output 50Ω

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply Voltage	VCC		6	V
Circuit Current	ICC		40	mA
Allowable Power Dissipation	PD		280	mW
Operating Temperature	Topr		-40 to +85	°C
Storage Temperature	Tstg		-55 to +150	°C

Recommended Operating Condition at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Supply Voltage	VCC		4.5	5	5.5	V
Operating Ambient Temperature	Topr		-40	+25	+85	°C

Marking : LC

Note) Pay attention to handling since it is liable to be affected by static electricity due to the high frequency process adopted.

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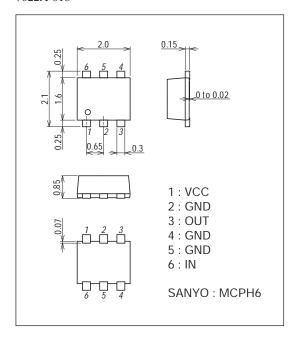
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Electrical Characteristics at Ta= 25° C, V_{CC}=5V, Zs=ZL= 50Ω

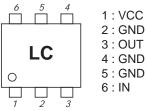
Parameter	Symbol	Conditions	Ratings			Linit
	Symbol	Conditions	min	typ	max	Unit
Circuit Current	ICC		14.0	19.0	25.0	mA
Power Gain	6	f=1GHz	24.0	26.5	29.0	dB
	Gp	f=2.2GHz	24.0	27.0	30.0	
Isolation	101	f=1GHz	31.0	33.0		dB
	ISL	f=2.2GHz	31.0	33.0		
Input Return Loss	RLin	f=1GHz	12.0	20.0		dB
		f=2.2GHz	10.0	14.0		
Output Return Loss	RLout	f=1GHz	12.0	20.0		dB
		f=2.2GHz	10.0	16.0		
Noise Figure	NF	f=1GHz		4.7	5.3	dB
		f=2.2GHz		4.7	5.3	
Gain 1dB Compression Output Power	Po(1dB)	f=1GHz	6.0	8.2		dBm
		f=2.2GHz	4.0	5.7		
Upper Limit Operating Frequency	fu	3dB down below flat gain at f =1GHz		3.3		GHz

Package Dimensions

unit : mm (typ) 7022A-018

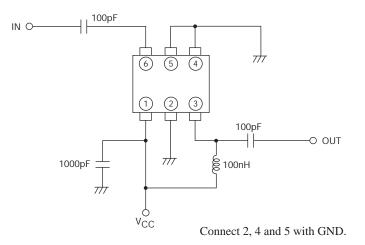


Marking

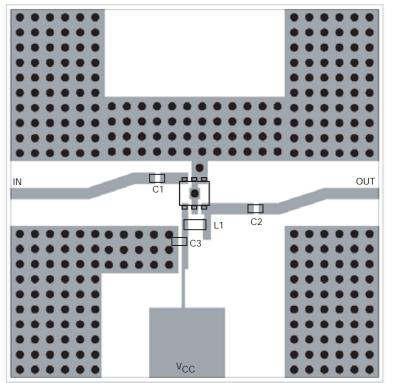


Top view

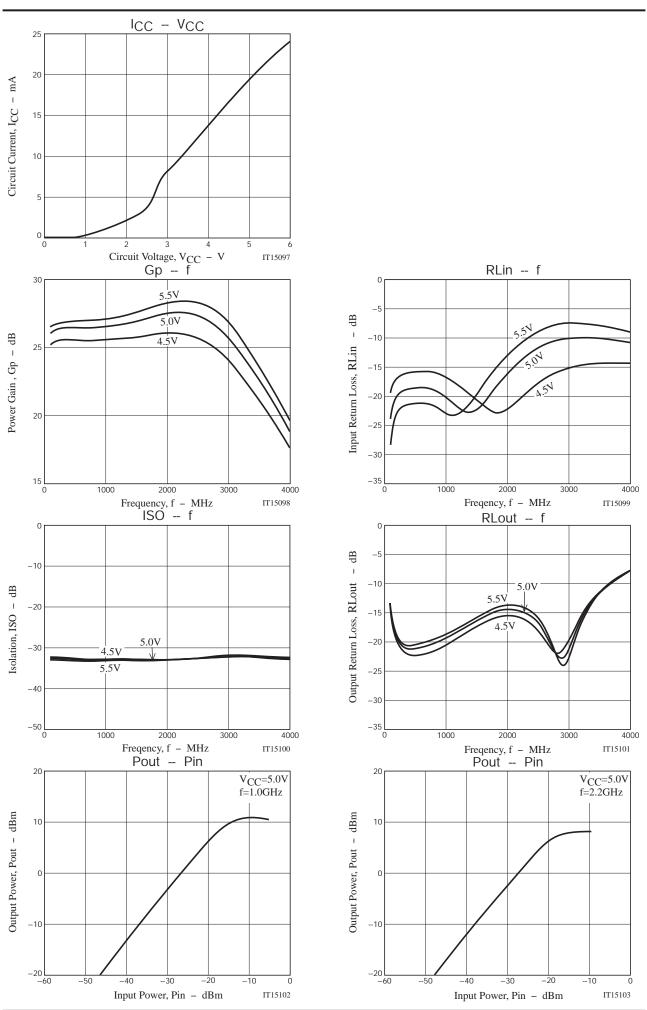
Test Circuit



Design of the Evaluation Board



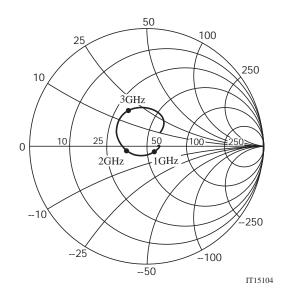
Symbol	Value
C1, C2	100pF
C3	1000pF
L1	100nH

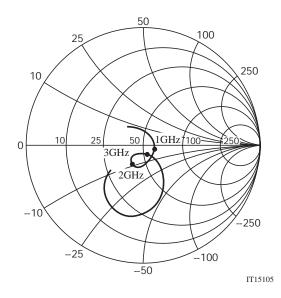


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